

Application No. Not Yet Assigned

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Docket No. M4065.0019/P019-A

Docket No.: M4065.0019/P019-A  
(PATENT)

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

In re Patent Application of:  
Leonard Forbes, et al.

Application No.: Not Yet Assigned

Group Art Unit: 2822

Filed: December 28, 2000

Examiner: M. Trinh

For: HIGH DENSITY SRAM CELL WITH  
LATCHED VERTICAL TRANSISTORS



6-23-01  
Payton

**INFORMATION DISCLOSURE STATEMENT (IDS)**

Assistant Commissioner for Patents  
Washington, DC 20231

Dear Sir:

Pursuant to 37 CFR 1.56, the attention of the Patent and Trademark Office is hereby directed to the references listed on the attached PTO/SB/08. It is respectfully requested that the information be expressly considered during the prosecution of this application, and that the references be made of record therein and appear among the "References Cited" on any patent to issue therefrom.

This Information Disclosure Statement accompanies the new patent application submitted herewith.

Those patent(s) or publication(s) listed in the attached form PTO/SB/08 (facsimile) are not supplied because they were previously cited by or submitted to the Office in a prior application no. 09/076,728 filed May 13, 1998 and relied upon in this application for an earlier filing date under 35 U.S.C. 120.

The Commissioner is hereby authorized to charge any deficiency in the fees filed, asserted to be filed or which should have been filed herewith (or with any paper hereafter filed in this application by this firm) to our Deposit Account No. 04-1073, under Order No. M4065.0019/P019-A. A duplicate copy of this paper is enclosed.

Dated: December 29, 2000

Respectfully submitted,

By 

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Attorneys for Applicant

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# INFORMATION DISCLOSURE CITATION IN AN APPLICATION

(Use several sheets if necessary)

Docket Number (Optional)  
M4065-0197-29Application Number  
Not Yet AssignedApplicant(s)  
Wendell P. Noble, Jr., et al.Filing Date  
Concurrently HerewithGroup Art Unit  
N/A
 13 U.S. PTO  
 08/17/99  
 12/29/99  
 12/29/99

## U.S. PATENT DOCUMENTS

| EXAMINER<br>INITIAL | REF | DOCUMENT NUMBER | DATE    | NAME            | CLASS | SUBCLASS | IF AFTER PROCEEDING |
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|  |     |                 |      |         |       |          | YES         | NO |
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# INFORMATION DISCLOSURE CITATION IN AN APPLICATION

(Use several sheets if necessary)

Docket Number (Optional)

M4065-019/P019

Applicant(s)

Wendell P. Noble, Jr., et al.

Filing Date

Concurrently Herewith

Application Number

Not Yet Assigned

Group/Art Unit

N/A

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## FOREIGN PATENT DOCUMENTS

|  | REF | DOCUMENT NUMBER | DATE | COUNTRY | CLASS | SUBCLASS | Translation |    |
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|  |     |                 |      |         |       |          | YES         | NO |
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| <b>INFORMATION DISCLOSURE CITATION<br/>IN AN APPLICATION</b>                  |  |  |      | Docket Number                 |  |  | Application Number |          |                               |
|   |  |  |      | M4065.019/P019                |  |  | Not Yet Assigned   |          |                               |
|   |  |  |      | Applicant(s)                  |  |  |                    |          |                               |
|   |  |  |      | Wendell P. Noble, Jr., et al. |  |  |                    |          |                               |
|   |  |  |      | Filing Date                   |  |  | Group Art Unit     |          |                               |
| Concurrently Herewith   |  |  |      | Not Assigned                  |  |  |                    |          |                               |
| U.S. PATENT DOCUMENTS   |  |  |      |                               |  |  |                    |          |                               |
| *EXAMINER<br>INITIAL  | REF  | DOCUMENT NO.   | DATE | NAME                          |  |  | CLASS              | SUBCLASS | FILING DATE<br>IF APPROPRIATE |
|   | No Citations to United States Patent Documents |  |      |                               |  |  |                    |          |                               |
|   |  |  |      |                               |  |  |                    |          |                               |
| FOREIGN PATENT DOCUMENTS  |  |  |      |                               |  |  |                    |          |                               |
|   | REF  | DOCUMENT   | DATE | NAME                          |  |  | CLASS              | SUBCLASS | Translations<br>YES NO        |
|   | No Citations to Foreign Patent Documents       |  |      |                               |  |  |                    |          |                               |
|   |  |  |      |                               |  |  |                    |          |                               |
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